## NSN 5961-01-439-4434

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-439-4434 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Terminal Length:** 0.120 inches **Overall Height:** 0.280 inches **Overall Width:** 0.300 inches **Mounting Facility Quantity:** 14 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 breakdown voltage, collector-to-emitter, base open and 40.0 working peak off-state voltage **Current Rating Per Characteristic:** 0.50 milliamperes source cutoff current of standard range **Power Rating Per Characteristic:** 1900.0 milliwatts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 175.0 degrees celsius case **Special Features:** 5 npn; ambient temp +25c; case plastic **Terminal Type And Quantity:** 14 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No